RF Devices and RF Circuit Design for Digital Communication

• Fundamentals of RF Circuits

- Lumped-element circuits: $\lambda \gg L$, L is a typical length of device.

e.g. $\lambda = 30$ cm for f = 1GHz

– Distributed-element circuits: $\lambda \sim L$

Lead Line becomes a coil and/or capacitance.

Historically **Rayleigh** analyzed an undersea cable based on distributed circuit concept.

→Image Impedance and Propagation Constant

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Agenda

• Fundamentals of RF Circuits

• Transmission Line

• Reflection Coefficient & Smith Chart

• Impedance Matching

• S-matrix Representation

• Amplifiers & Unilateral Gain

RF Devices

• Digital RF

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- Basic distributed element: **Transmission Line**

F-matrix of Transmission Line

$$F = \begin{bmatrix} \cos\theta & jZ_0 \sin\theta \\ j\sin\theta/Z_0 & \cos\theta \end{bmatrix}$$

 Z_0 : Characteristic impedance of Transmission Line

 θ : Phase delay $\left(=\beta\ell=\omega\sqrt{\varepsilon\mu}\ell=\omega\ell/\nu\right)$

 ℓ : length

v: velocity

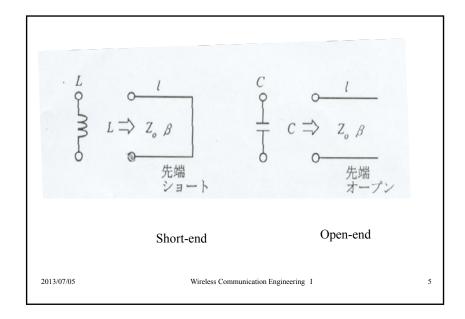
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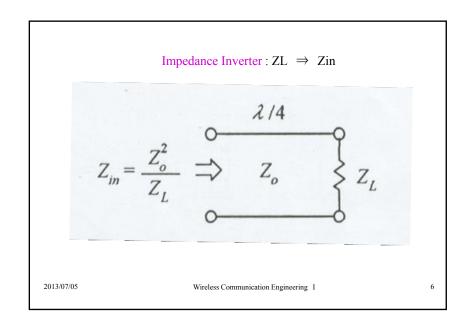
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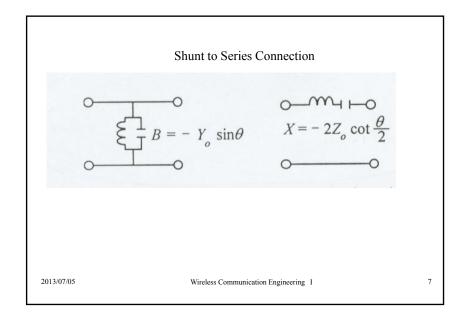


Inductance, Capacitance, Filter, Impedance Transformer

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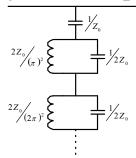
Impedance Matrix of Transmission Line

$$Z = \frac{Z_o}{j\sin\theta} \begin{bmatrix} \cos\theta & 1\\ 1 & \cos\theta \end{bmatrix}$$
$$= \frac{Z_o}{j} \left\{ \frac{1}{\theta} \begin{bmatrix} 1 & 1\\ 1 & 1 \end{bmatrix} + \sum_{n=1}^{\infty} \frac{2\theta}{\theta^2 - (n\pi)^2} \begin{bmatrix} 1 & (-1)^n\\ (-1)^n & 1 \end{bmatrix} \right\}$$

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Equivalent Circuit of Transmission Line by Foster Expansion



A Series Connection of Parallel Resonance Circuits

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-Short (Open) - circuited load: \rightarrow Reactance element $X_{\text{in}} = Z_0 \tan \theta$: short-circuited load

 $0 < \theta < \pi/2$: Inductance $\theta \approx \pi/2$: Parallel resonance circuit $\pi/2 < \theta < \pi$: Capacitance

- -Stub
- -Quater-wavelength Transformer
- → Matching coating lense

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(a) Z_0 Z_0

• Reflection coefficient (Γ) and Load Impedance (Z_L)

$$\Gamma = \frac{Z_L - Z_0}{Z_L + Z_0}$$
: Bilinear mapping

 Z_0 : reference characteristic impedance

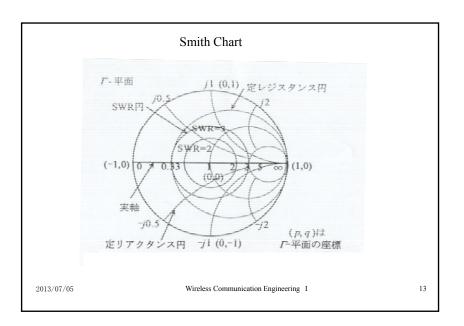
Circle to Circle Mapping (Moebius Transform)

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$$|\operatorname{Re}(Z_L)>0:|\Gamma|<1 \text{ (Passive)}|$$

$$|\operatorname{Re}(Z_L) = 0: |\Gamma| = 1 \text{ (Lossless)}$$

Reflection type phase modulator

$$|\operatorname{Re}(Z_L) < 0: |\Gamma| > 1 \text{ (Active)}|$$

Reflectiontypeamplifier

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• Voltage Standing Wave Ratio (VSWR)≥1

$$VSWR = \frac{V_{\text{max}}}{V_{\text{min}}} = \frac{V_i + V_r}{V_i - V_r}$$

$$\left|\Gamma\right| = \frac{V_r}{V_i} = \frac{VSWR - 1}{VSWR + 1}$$

 V_i : incident wave

 V_r : reflected wave

• Special Terminations / Circuits

-Matched load:
$$(Z_L = Z_0) \rightarrow \Gamma = 0$$
, No reflection

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- Smith-chart and its usage

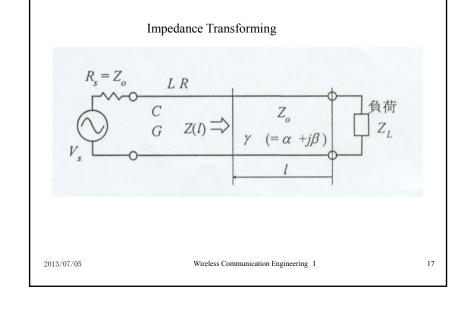
• Smith-chart (Bell Lab. 1950's)

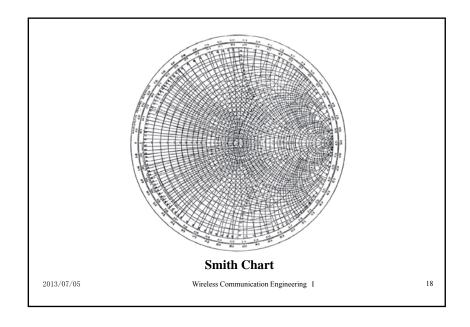
$$Z_{\rm in} = Z_0 \frac{Z_L + jZ_0 \tan \theta}{Z_0 + jZ_L \tan \theta}$$

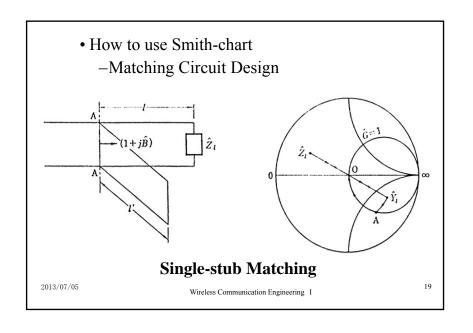
$$Z_{L} \to \widetilde{Z}_{L} = \frac{Z_{L}}{Z_{0}} \to \Gamma_{L} = \frac{\widetilde{Z}_{L} - 1}{\widetilde{Z}_{L} + 1} \to$$

$$\Gamma_{\text{in}} = \Gamma_{L} \exp^{-j2\theta} \to \widetilde{Z}_{\text{in}} = \frac{1 + \Gamma_{\text{in}}}{1 - \Gamma_{\text{in}}} \to Z_{\text{in}}$$

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- Microstrip Line

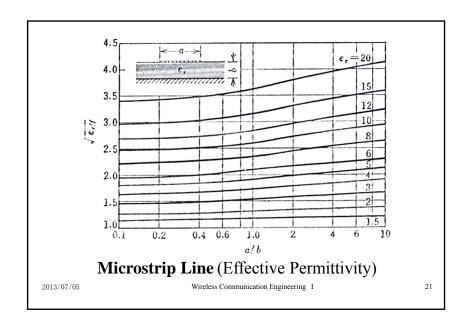
- Effective permittivity and guided wavelength
- Characteristic Impedance
- Several notes : Finite conductor thickness

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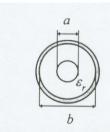
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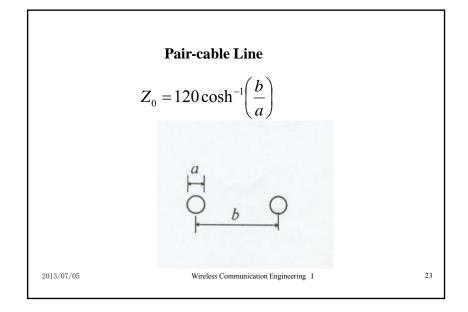


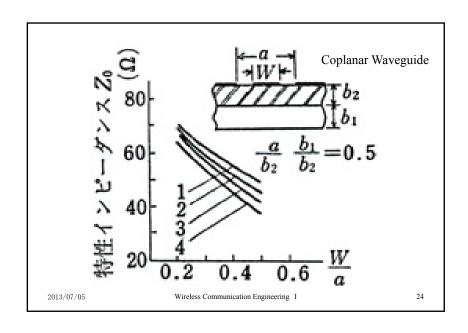
Coaxial Line

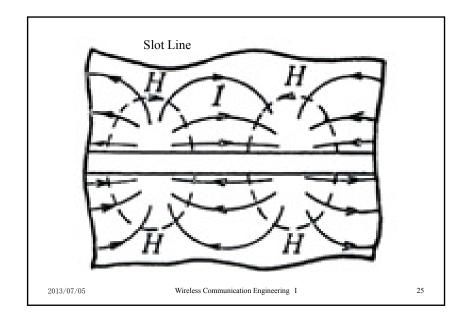
$$Z_0 = \frac{138}{\sqrt{\varepsilon_r}} \log \frac{b}{a}$$



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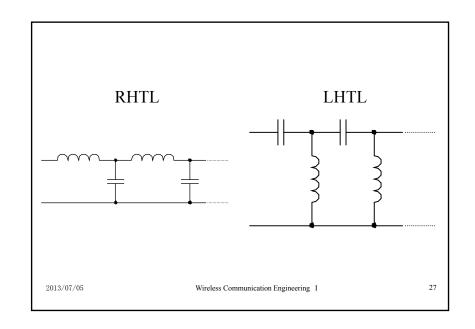


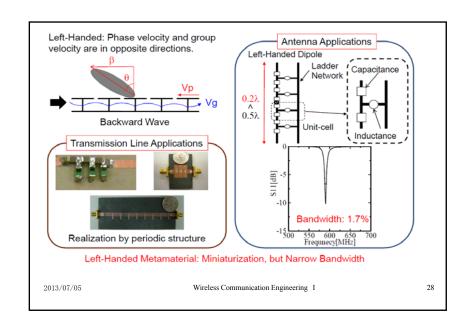


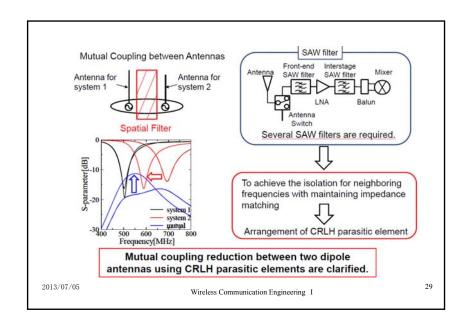
Meta Material

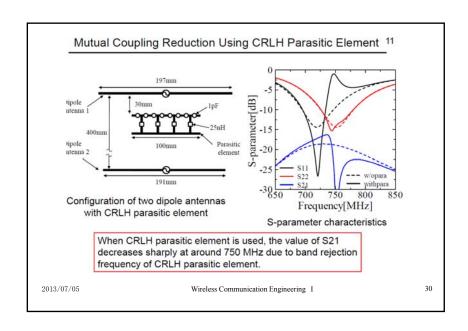
- Right-Hand Transmission Line
- Left-Hand Transmission Line
- Composite RH/LH Transmission Line
- Compact Directional Coupler
- Super-Lense

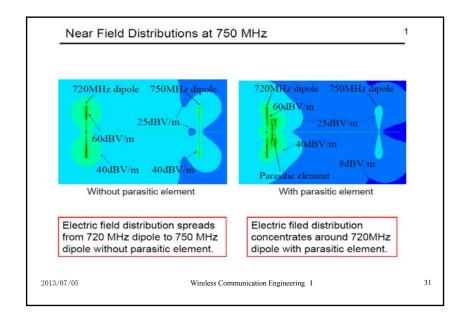
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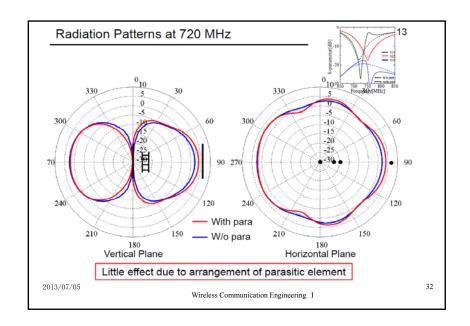


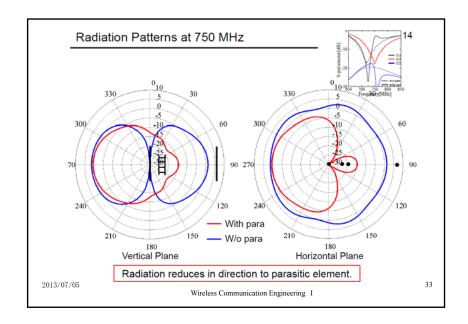












• S-parameter and RF Circuit Design

-S-parameter (1950's ← Nuclear Physics)

voltage, current \rightarrow incident wave, reflected wave impedance \rightarrow reflection coefficient impedance matrix \rightarrow scattering matrix, [S]

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For lossless circuit, **S-matrix** = **Unitary Matrix**

For lossy circuit, $S^{\dagger}S \leq I$ Para-unitary

For Reciprocal circuit, S-matrix = Symmetric matrix

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SVD (Singular Value Decomposition)

$$S=U^{\dagger}DV$$
 (Youla)

U,V: Unitary matrix (Lossless Circuit)

D: Diagonal Matrix (\rightarrow Isolated n-port circuit)

$$D = Diag[\lambda_1, ..., \lambda_n]$$

$$\lambda_i < 1$$
 \rightarrow resistance

$$\lambda_i > 1$$
 \rightarrow negative resistance

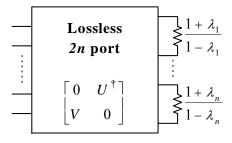
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Generalization of Darlington realization



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- Basics of RF Circuit Design
 - Impedance Matching Circuits

$$Z_g = Z_L^*$$

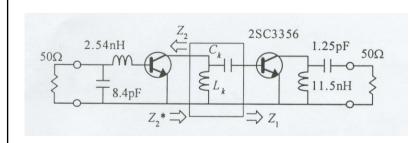
 Z_g : Generator Impedance

 Z_L : Load Impedance

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Conjugate Matching



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Unilateral Transducer Gain G_{TU}

(For the case, $S_{12} = 0$ Reverse transfer coefficient from output to input)

FET
$$S$$
 - parameter $\begin{vmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{vmatrix}$

$$G_{TU} = \frac{\left(1 - \left|\Gamma_{s}\right|^{2}\right)}{\left|1 - S_{11}\Gamma_{s}\right|^{2}} \cdot \left|S_{21}\right|^{2} \cdot \frac{\left(1 - \left|\Gamma_{L}\right|^{2}\right)}{\left|1 - S_{22}\Gamma_{L}\right|^{2}}$$

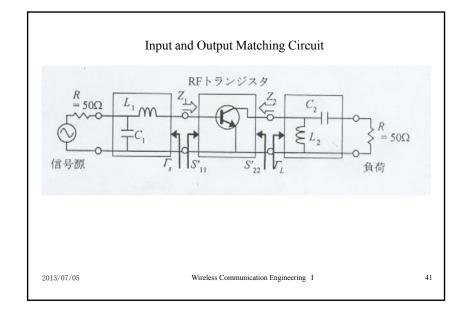
$$= G_{s} \cdot G_{0} \cdot G_{L}$$

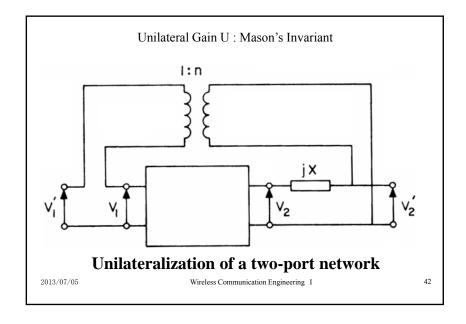
$$G_{TU,\text{max}} = \frac{1}{1 - |S_{11}|^2} \cdot |S_{21}|^2 \cdot \frac{1}{1 - |S_{22}|^2}$$

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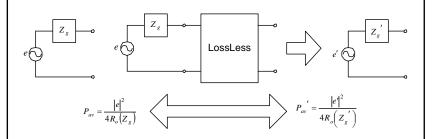
Circuit Invariant

- Unilateral Gain (U)
- Maximum Available Gain (MAG)
- Noise Measure (M)
- 2-state diode (m, Q)
- Circulator Invariant (α)
- Directional Coupler Invariant (K)

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Available Power



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2-state device

- On-state impedance Z1, Off-state impedance Z2
- M= $|Z1-Z2|/|Z1+Z2*| \Rightarrow Invariant w.r.t. Lossless$ 2port connection
- M= $|\Gamma 1-\Gamma 2|$ / $|1-\Gamma 1\Gamma 2^*|$ \Rightarrow Optimum BPSK Direct Modulation Design

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RF Devices

- Passive Components / Circuits
 - Reactance Elements
 - Distributed-element: Open-stub, Short-stub, Line Gap Wide Line, Narrow Line
 - Lumped-element: Spiral Inductor, Gap Capacitor, Thin Film Capacitor

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Attenuators:

Thin Film Resistor

• Impedance Transformers: Quarter-wavelength Impedance Transformer

$$Z_{\rm in} = \frac{Z_0^2}{Z_L}$$

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• Resonator:

- -Lumped Element Type
- -Microstrip Line Type
- -Dielectric Resonator Type (Good Ceramic)

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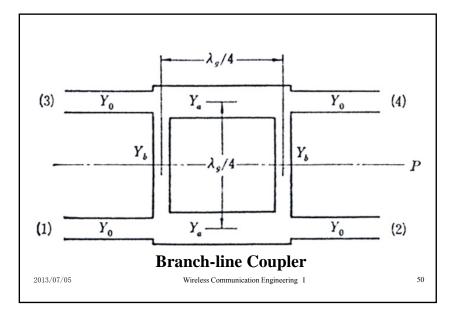
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Distributing Components / Circuits

• Directional Coupler:

Coupled Line TypeInter-digital TypeBranch Line TypeRat-race Type

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• Power Divider / Combiner:

Perfect Matching + Perfect Isolation → Absorbing Resistance

Power Monitor, Balanced Type Modulator / Amplifier / Mixer

→ Perfect Directional Coupler with 90deg. Phase Difference

Lossless reciprocal matched two-fold symmetry 4-port

- Filter
 - -Low Pass Filter (LPF):
 - L, C Ladder Filter
 - Band Pass Filter (BPF):Half-wavelength transmission line resonator
 - -Band Stop Filter (BSF):

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• Transmission Scheme and RF Circuits

Objectives: Low Power Consumption, Higher Frequency, Small Size, Low Weight

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– Basic configuration of RF Circuits: Super-Heterodyne

Mixer: Up-conversion Down-conversion

Amplifier: Power Amp. (TX) Low Noise Amp. (RX)

Oscillator: Local Oscillator

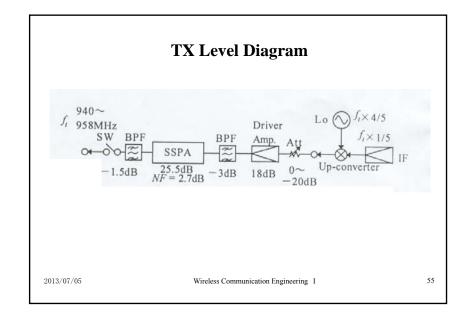
Filter: LPF, BPF

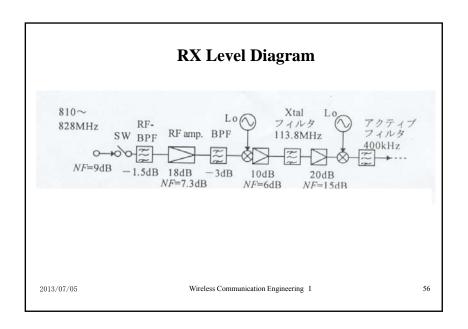
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Block diagram of Transceiver SAW FTアンプ BPF ミクサ フィルタ FTアンプ フィルタ Wireless Communication Engineering 1 SAW FT フィルタ FT CXO FT CXO





Digital RF Circuits

- RF-CMOS Technology
- Analog Signal Processing & Digital Signal Processing
- Continuous Time & Discrete Time
- Direct Conversion & Sampling
- Built-in RF Self Test & Calibration

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